TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SG17FE

#### Schmitt Buffer

#### **Features**

• High-level output current:  $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$ 

at  $V_{CC} = 3.0 \text{ V}$ 

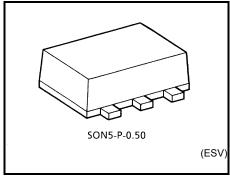
• High-speed operation: t<sub>pd</sub> = 3.7 ns (typ.)

at  $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$ 

• Operating voltage range: V<sub>CC</sub> = 0.9~3.6 V

• 5.5-V tolerant input.

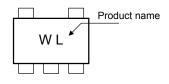
• 3.6-V power down protection output.

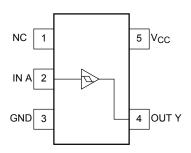


Weight: 0.003 g (typ.)

#### Marking

#### Pin Assignment (top view)





#### **Absolute Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Value	Unit	
Power supply voltage	Vcc	-0.5~4.6	V	
DC input voltage	V <sub>IN</sub>	-0.5~7.0	٧	
DC output voltage	Vour	-0.5~4.6 (Note 1)	٧	
DC output voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5 (Note 2)		
Input diode current	lıĸ	-20	mA	
Output diode current	lok	-20 (Note 3)	mA	
DC output current	lout	±25	mA	
DC V <sub>CC</sub> /ground current	Icc	±50	mA	
Power dissipation	PD	150	mW	
Storage temperature	T <sub>stg</sub>	-65~150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

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Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V<sub>CC</sub> = 0V

Note 2: High or Low State. IOUT abusolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND

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# **IEC Logic Symbol**

#### mbol Truth Table



Α	Y
L	L
Н	Н

## **Operating Ranges**

Characteristics	Symbol	Value	Unit	
Power supply voltage	V <sub>CC</sub>	. 0.9~3.6	V	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V	0~5.5 (Note 4)	V	
	V <sub>OUT</sub>	0~V <sub>CC</sub> (Note 5)	V	
Output Current		±8.0 (Note 6)		
		±4.0 (Note 7)		
		±3.0 (Note 8)	A	
	I <sub>OH</sub> /I <sub>OL</sub>	±1.7 (Note 9)	mA	
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T <sub>opr</sub>	-40~85	°C	

Note 4:  $V_{CC} = 0.0 \text{ V}$ 

Note 5: High or Low state

Note 6: V<sub>CC</sub> = 3.0~3.6 V

Note 7:  $V_{CC} = 2.3 \sim 2.7 \text{ V}$ 

Note 8:  $V_{CC} = 1.65 \sim 1.95 \text{ V}$ 

Note 9:  $V_{CC} = 1.4 \sim 1.6 \text{ V}$ 

Note 10:  $V_{CC} = 1.1 \sim 1.3 \text{ V}$ 

Note 11:  $V_{CC} = 0.9 \text{ V}$ 

## **Electrical Characteristics**

## **DC Characteristics**

Characteristics S		Symbol Test C		t Candition	Condition		Ta = 25°C			Ta = -40~85°C	
		Syllibol	res	Test Condition		Min	Тур.	Max	Min	Max	Unit
Positive threshold voltage					_	_	0.73	_	0.80		
				1.1	_	_	0.86	_	0.93	-	
	VP				_		1.07	_	1.12		
		_		1.65	_	_	1.23	_	1.25		
					2.3	_	_	1.66	_	1.68	v
Input voltage					3.0	_		2.14	_	2.15	
Input voltage					0.9	0.18	_	_	0.07	_	
					1.1	0.26	_	_	0.18	_	
	Negative				1.4	0.36	_	_	0.31		
	threshold voltage	V <sub>N</sub>		_	1.65	0.45	_	_	0.41	_	
					2.3	0.69		_	0.64	_	
					3.0	0.96	_	_	0.91	_	
					0.9	0.20		0.38	0.15	0.53	· v
					1.1	0.25	_	0.41	0.21	0.53	
Llyotoropia	voltage	V.				0.35	_	0.48	0.34	0.57	
Hysteresis	voitage	V <sub>H</sub>	_		1.65	0.42	_	0.56	0.40	0.60	
					2.3	0.60		0.74	0.61	0.76	
					3.0	0.79	_	0.93	0.80	0.94	
			VIN = VIH	I <sub>OH</sub> =-0.02 mA	0.9	0.75	_	_	0.75	-	
				$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75		
	High level	Vон		$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_	
				$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V <sub>C</sub> C -0.45	_	_	V <sub>C</sub> C -0.45	_	
				$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0	_	_	2.0	_	
Output voltage				$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48		_	2.48	_	
p9 -				$I_{OL} = 0.02 \text{ mA}$	0.9	—		0.1	_	0.1	
				I <sub>OL</sub> = 0.3 mA	1.1~1.3	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	
L	Low level	V <sub>OL</sub>		I <sub>OL</sub> = 1.7 mA	1.4~1.6	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	
				$I_{OL} = 3.0 \text{ mA}$	1.65~ 1.95			0.45		0.45	
				$I_{OL} = 4.0 \text{ mA}$	2.3~2.7	_	_	0.4	_	0.4	
				$I_{OL} = 8.0 \text{ mA}$	3.0~3.6	_	_	0.4	_	0.4	
Input leakage cu	rrent	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.	.5V	0~3.6	_		±0.1	_	±1.0	μΑ
Power off leakage current I <sub>OFF</sub>		V <sub>IN</sub> = 0~5. V <sub>OUT</sub> = 0~	V <sub>IN</sub> = 0~5.5V V <sub>OUT</sub> = 0~3.6V		_		1.0	_	10.0	μΑ	
Quiescent supply current I <sub>CC</sub>		$V_{IN} = \overline{V_{CC}}$	V <sub>IN</sub> = V <sub>CC</sub> or GND		_	_	1.0	_	10.0	μΑ	

# AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
		$\begin{array}{c} C_L = 10 \; pF, \\ R_L = 1 \; M\Omega \end{array}$	0.9	_	27.3	_	_	_	
			1.1~1.3	_	13.0	22.6	1.0	35.9	
			1.4~1.6	_	7.5	10.5	1.0	11.3	ns
			1.65~ 1.95	_	6.0	7.8	1.0	8.2	
			2.3~2.7		4.3	5.4	1.0	5.8	
			3.0~3.6		3.5	4.4	1.0	4.6	
		$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		29.5		_	_	
Propagation delay time	<sup>t</sup> pLH <sup>t</sup> pHL		1.1~1.3	_	14.3	25.1	1.0	41.8	
			1.4~1.6	_	8.0	11.5	1.0	12.6	
			1.65~ 1.95		6.3	8.4	1.0	8.7	
			2.3~2.7	_	4.6	5.7	1.0	6.1	
			3.0~3.6		3.7	4.6	1.0	5.0	
		$C_L$ = 30 pF, $R_L$ = 1 M $\Omega$	0.9	_	40.5	_		—	
			1.1~1.3	_	19.6	35.7	1.0	58.1	
			1.4~1.6	_	10.7	15.8	1.0	17.6	
			1.65~ 1.95		7.8	10.7	1.0	11.7	
			2.3~2.7	_	5.4	6.9	1.0	8.1	
			3.0~3.6	_	4.3	5.2	1.0	6.1	
Input capacitance	C <sub>IN</sub>	_	3.6	_	3	_	_	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 12)	0.9 ~ 3.6	-	7		_	_	pF

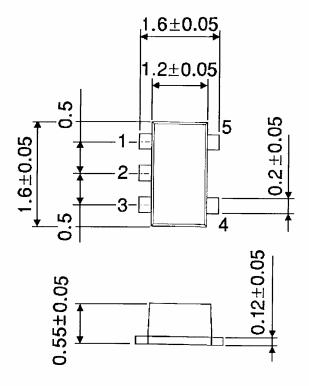
Note 12: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $ICC (opr.) = CPD \cdot VCC \cdot fIN + ICC$ 

# **Package Dimensions**

SON5-P-0.50 Unit: mm



Weight: 0.003 g (typ.)

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20070701-EN GENERAL

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